

SCI7630M/C Series

Switching Regulator



●Step-up Switching Regulator

(1.5V → 2.0, 2.2, 2.35, 2.4, 2.7, 2.8, 3.0, 3.1, 3.5, 3.7, 4.2 ,5.0V)

●Low Operating Voltage(Min 0.9V)

●Voltage Detecting function, Battery Back-up function

(SCI7363/7632/7635/7636/7639M/C)

■ DESCRIPTION

The SCI7630M/C Series offers a variety of high-efficiency and low current dissipation switching regulators produced by the silicon gate CMOS process.(An external inductor is used to implement the boosting function.)Each SCI7630M/C basically consists of a reference voltage supply, comparator, and inductor driving transistors. Its output voltage is fixed internally.

The SCI7630M/C Series operates with low current dissipation and low voltage. Its optional features include voltage detecting function, battery back-up function, and stand-by function. It is thus suited for controlling the power supply of portable or small size equipment that requires high operating efficiency.

The SCI7630M/C series has four major variation. The SCI7635M/C, the SCI7636M/C and the SCI7637M/C are driven by external clock signals. The SCI7631M/C, the SCI7632M/C, the SCI7638M/C and the SCI7639M/C operate by the clock signal generated by an on-chip CR oscillation circuit. The SCI7633M/C and the SCI7634M/C operate by the clock signal generated by a crystal oscillation circuit. And another feature of the SCI7636M/C, the SCI7638M/C and the SCI7639M/C is its output voltage which has temperature characteristics matching the properties of an LCD, making it suitable as the power supply of a product using an LCD.

■ FEATURES

- Low operating voltage Min. 0.9V
- Low current dissipation Typ. 5 μ A(SCI7635M/C)
- Low stand-by current Typ. 3 μ A
- High accurate voltage detection 1.05V(0.05V(SCI7631M/C, SCI7632M/C, SCI7635M/C, SCI7636M/C, SCI7638M/C, SCI7639M/C, SCI763AM/C))
- Be able to power off
- Battery back-up function(SCI7631M/C, SCI7632M/C, SCI7635M/C, SCI7636M/C, SCI7637M/C, SCI7639M/C)
- Built-in CR oscillation circuit(SCI7631M/C, SCI7632M/C, SCI7638M/C, SCI7639M/C)
- Power on clean(SCI7631M/C, SCI7638M/C)
- Response compensation inputs(SCI7632M/C, SCI7638M/C, SCI7639M/C, SCI763AM/C)
- Temperature gradient of output voltage for LCD(SCI7636M/C, SCI7638M/C, SCI7639M/C)
- Package SCI763M: SOP3-8pin(plastic)
SCI763C: DIP-8pin(plastic)

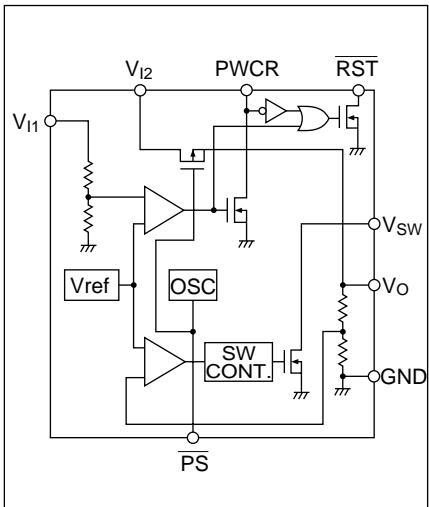
■ LINE UP

Type No.	Input voltage	Output voltage	Oscillation for booster	Voltage detecting function	Power-on clear	Battery back-up	Ripple noise suppression input	Output voltage temp gradient	Package
SCI7631C _{CA}	1.5V (0.9Vmin.)	2.0V	internal CR oscillation	available	available	available	-	-	DIP-8pin
SCI7631M _{CA}		2.2V							SOP3-8pin
SCI7631C _{HA}		2.4V							DIP-8pin
SCI7631M _{HA}		3.0V							SOP3-8pin
SCI7631C _{LA}		3.5V							DIP-8pin
SCI7631M _{LA}		4.2V							SOP3-8pin
SCI7631C _{BA}		5.0V							DIP-8pin
SCI7631M _{BA}		2.8V							SOP3-8pin
SCI7631C _{KA}		5.0V							DIP-8pin
SCI7631M _{KA}		3.0V							SOP3-8pin
SCI7631C _{AA}	1.5V (0.9Vmin.)	3.5V	internal CR oscillation	available	available	available	-	-	DIP-8pin
SCI7631M _{AA}		5.0V							SOP3-8pin
SCI7632C _{RA}	1.5V (0.9Vmin.)	2.8V			available	-	available	available	DIP-8pin
SCI7632M _{RA}		5.0V							SOP3-8pin
SCI7632C _{AA}	1.5V (0.9Vmin.)	3.0V	crystal oscillation	-	-	-	-	-	DIP-8pin
SCI7632M _{AA}		5.0V							SOP3-8pin
SCI7633C _{BA}	1.5V (0.9Vmin.)	3.0V		-	-	-	-	-	DIP-8pin
SCI7633M _{BA}		5.0V							SOP3-8pin
SCI7633C _{AA}	1.5V (0.9Vmin.)	3.0V			-	-	-	-	DIP-8pin
SCI7633M _{AA}		5.0V							SOP3-8pin
SCI7634C _{NA}	1.5V (0.9Vmin.)	2.35V	crystal oscillation	-	-	-	available	-	DIP-8pin
SCI7634M _{NA}		2.35V							SOP3-8pin
SCI7635C _{CA}	1.5V (0.9Vmin.)	2.0V	external clock input	available	-	available	-	-	DIP-8pin
SCI7635M _{CA}		2.7V							SOP3-8pin
SCI7635C _{FA}		3.0V							DIP-8pin
SCI7635M _{FA}		3.0V							SOP3-8pin
SCI7635C _{BA}		5.0V							DIP-8pin
SCI7635M _{BA}	1.5V (0.9Vmin.)	3.0V	external clock input	available	-	available	-	-	SOP3-8pin
SCI7635C _{AA}		3.1V							DIP-8pin
SCI7635M _{AA}		5.0V							SOP3-8pin
SCI7636C _{BA}	1.5V (0.9Vmin.)	3.0V	external clock input	available	-	available	-	-3.0mV/°C	DIP-8pin
SCI7636M _{BA}		3.1V							SOP3-8pin
SCI7636C _{JA}		5.0V							-6.0mV/°C
SCI7636M _{JA}	1.5V (0.9Vmin.)	3.0V	external clock input	available	-	available	-	-5.0mV/°C	DIP-8pin
SCI7636C _{AA}		3.1V							SOP3-8pin
SCI7636M _{AA}		5.0V							DIP-8pin
SCI7637C _{NA}	1.5V (0.9Vmin.)	2.35V	external clock input	-	-	available	available	-	DIP-8pin
SCI7637M _{NA}		2.7V							SOP3-8pin
SCI7637C _{FA}		3.0V							DIP-8pin
SCI7637M _{FA}	1.5V (0.9Vmin.)	2.35V	internal CR oscillation	available	-	available	-	-4.5mV/°C	DIP-8pin
SCI7637C _{BA}		2.7V							SOP3-8pin
SCI7637M _{BA}		3.0V							DIP-8pin
SCI7638C _{HA}	1.5V (0.9Vmin.)	2.2V	internal CR oscillation	available	-	available	-	-4.0mV/°C	DIP-8pin
SCI7638M _{HA}		2.4V							SOP3-8pin
SCI7638C _{LA}		2.7V							-6.0mV/°C
SCI7638M _{LA}	1.5V (0.9Vmin.)	2.8V	internal CR oscillation	available	-	available	-	-5.5mV/°C	DIP-8pin
SCI7638C _{FA}		3.0V							SOP3-8pin
SCI7638M _{FA}		4.2V							DIP-8pin
SCI7639C _{RA}	1.5V (0.9Vmin.)	2.8V	internal CR oscillation	available	-	available	available	-	SOP3-8pin
SCI7639M _{RA}		3.7V							SOP3-8pin
SCI763AM _{SA}	1.5V	3.7V	internal CR oscillation	available	-	-	available	-	SOP3-8pin
SCI763AM _{PA}	1.5V (0.9Vmin.)	4.2V	internal CR oscillation	available	-	-	available	-	SOP3-8pin

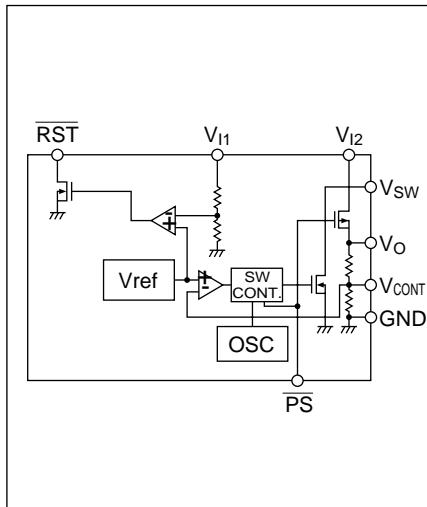
SCI7630M/C

■ BLOCK DIAGRAM

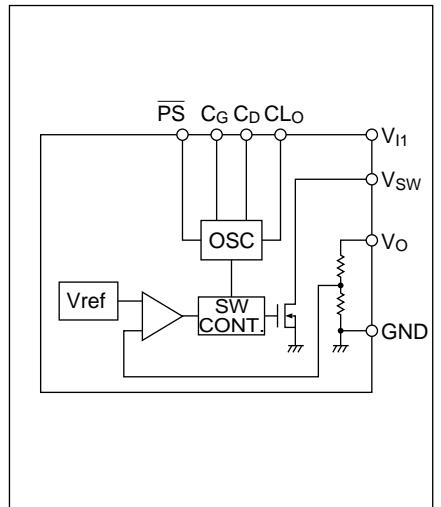
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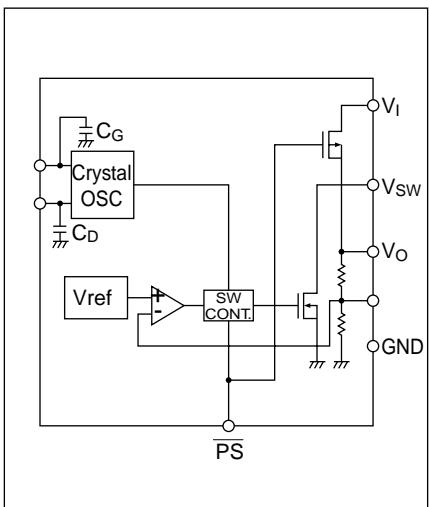
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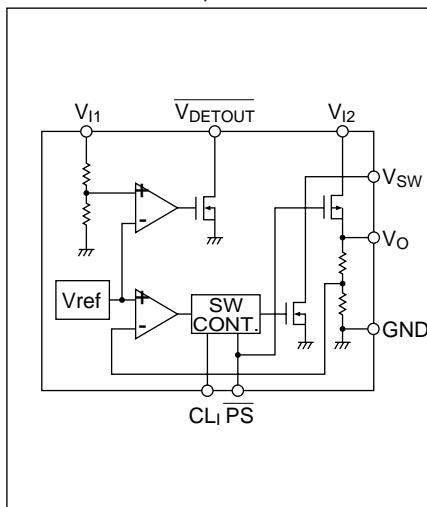
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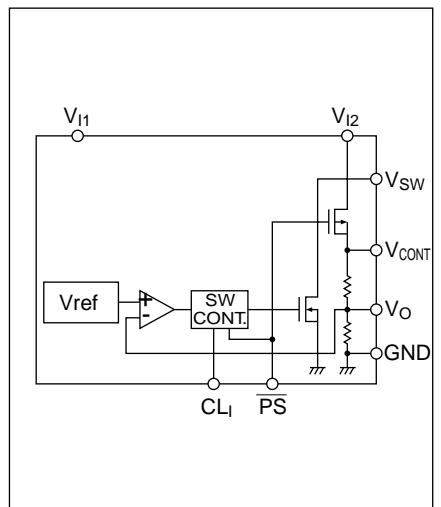
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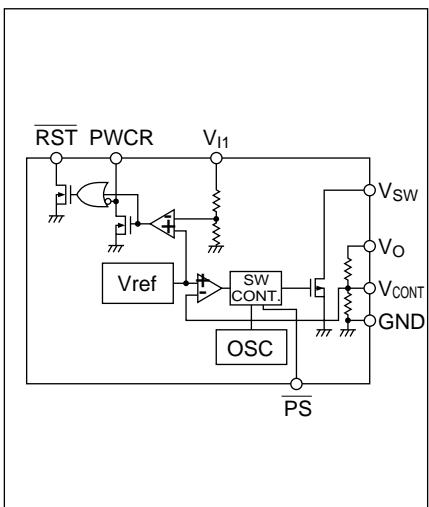
●SCI7635M/C, SCI7636M/C



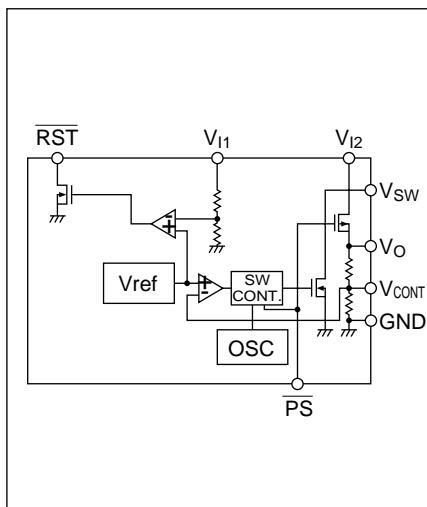
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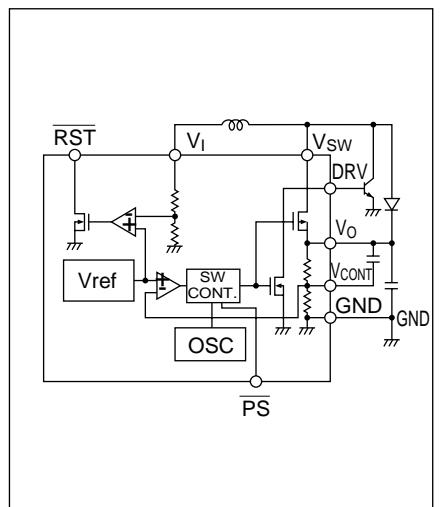
●SCI7638M/C



●SCI7639M/C

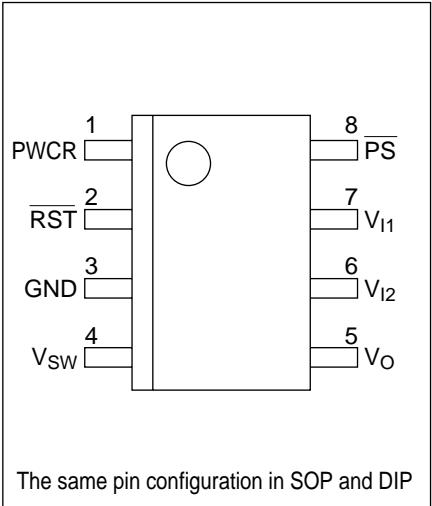


●SCI763AM

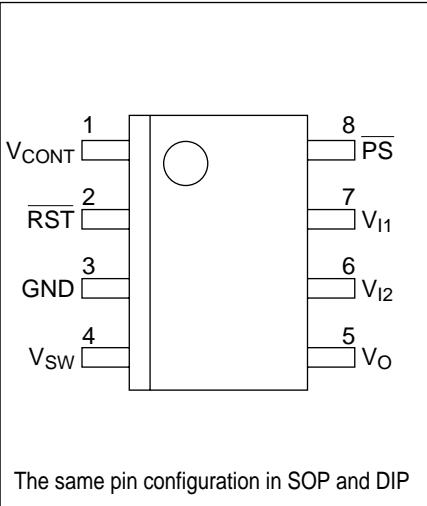


■ PIN CONFIGURATION

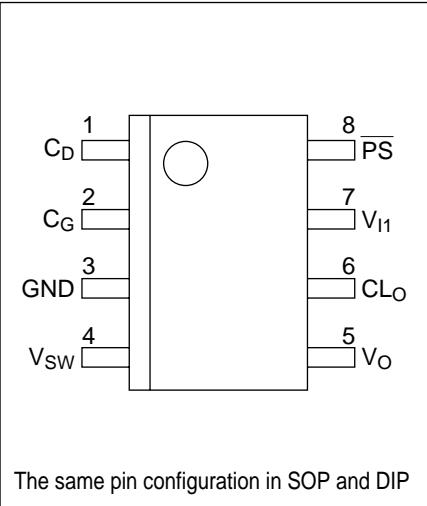
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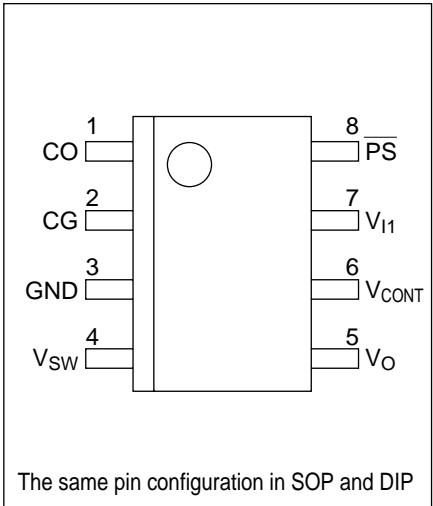
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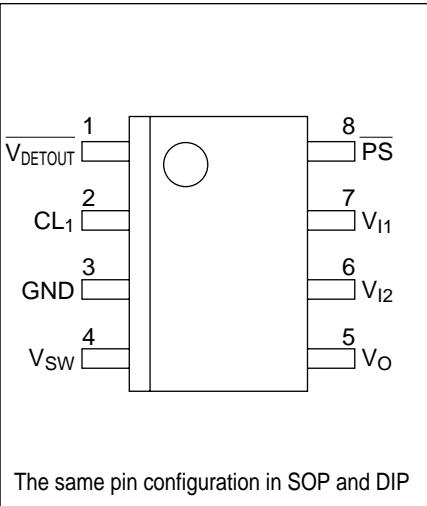
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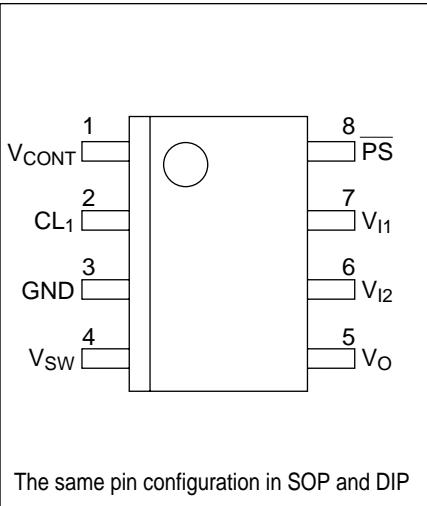
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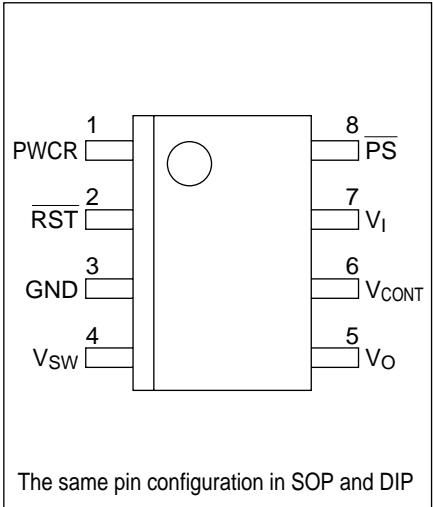
●SCI7635M/C, SCI7636M/C



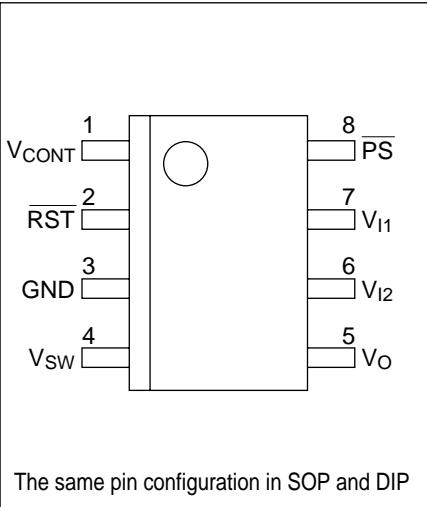
●SCI7637M/C



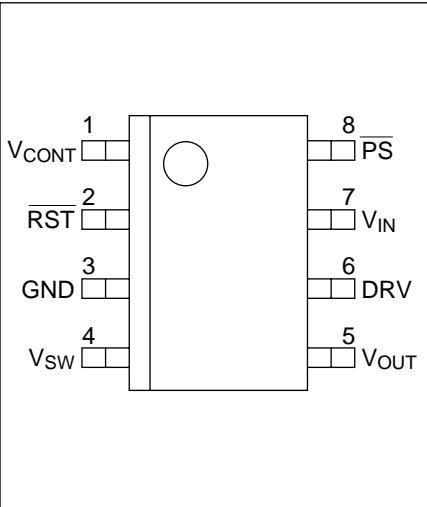
●SCI7638M/C



●SCI7639M/C



●SCI763AM



■ PIN DESCRIPTION

Pin Name	Function	Pin Name	Function
V _{I1}	Power supply for booster(positive)	\overline{RST}	Reset signal output(voltage detection)
V _{I2}	Power Supply for back-up(positive)	C _D	Crystal oscillator terminal(Drain)
V _O	Output voltage	C _G	Crystal oscillator terminal(Gate)
V _{SW}	Terminal for connection of inductor for booster	C _{L_O}	Clock pulse output
\overline{PS}	Power save control	¹ C _{L_I}	Clock pulse input for booster
V _{DETOUT}	Output pin of voltage detection	² GND	Power supply(GND)
PWCR	Power on clear	³ V _{CONT}	⁴ Comparator input terminal

*1. Stand-by mode and back-up function (back-up function is available to SCI7631M/C, SCI7632M/C, SCI7635M/C, SCI7636M/C, SCI7637M/C, SCI7639M/C).

The device can be set into stand-by mode by connecting the \overline{PS} pin to GND level. In the stand-by mode, the on-chip back-up switch turns on and the input voltage connected to the V_{I2} pin is output to the V_O pin with the boosting operation at rest. The \overline{PS} pin is internally pulled up, and must be held open when its control is unnecessary. (Connecting the voltage detection output to the \overline{PS} pin validates the back-up function.)

*2. Voltage detecting function (SCI7632M/C, SCI7635M/C, SCI7636M/C, SCI7639M/C)

The RST/V_{DETOUT} pin provides an N-channel open drain output. It is in open state when the voltage to the V_{I1} pin exceeds the detection voltage. If the voltage to the V_{I1} pin decreases below the detection voltage, the N-channel transistor of the output turns on to develop GND level. The detection voltage is 1.05V \pm 0.05V, which is fixed internally.

*3. Power on clear function (SCI7631M/C, SCI7638M/C) (voltage detection function)

See the SCI7631M/C example of application. For a system with an external resistor R₁ and capacitor C₁ connected to the PWCR pin and a pull-up resistor to the \overline{RST} pin, a reset pulse whose width can flexibly be selected by R₁ and C₁ is obtained after acquisition of normal output by boosting operation. This enables the system (for example, a microcomputer), connected to the \overline{RST} pin, to be correctly reset.

With the PWCR pin connected to the V_O pin, the \overline{RST} pin stays open when V_{I1} exceeds the detection voltage, and develops a GND level output when V_{I1} is smaller than the detection voltage.

*4. The ripple voltage generated on the boost output voltage can be reduced by connecting response compensation capacitor between the comparator input terminals V_{CONT} and the V_O. (SCI7632M/C, SCI7634M/C, SCI7637M/C, SCI7638M/C, SCI7639M/C)

■ ABSOLUTE MAXIMUM RATINGS

(GND=0V, Ta=25°C)

Rating	Symbol	Value	Unit
input voltage	V _{I1}	7	V
Output current	I _O	100	mA
Output voltage	V _O	7	V
Power dissipation	P _d	200(SOP3-8pin) 300(DIP-8pin)	mW
Operating temperature	T _{opr}	- 30 to 85	°C
Storage temperature	T _{stg}	- 65 to 150	°C
Soldering temperature and time	T _{sol}	260°C, 10s(at lead)	-

Note: When SOP 3-8pin is soldered in the solder-reflow process, be sure to maintain the reflow furnace temperature at the curve shown in "Fig. 3-5 Reflow Furnace Temperature Curve" of DATA BOOK. And SOP3-8pin can not be exposed to high temperature of the solder dipping.

■ ELECTRICAL CHARACTERISTICS

●SCI7631M/CAA, SCI7632M/CAA, SCI7633M/CAA, SCI7635M/CAA, SCI7636M/CAA
 (GND=0V, Ta=25°C)

Parameter	Symbol	Condition		Min.	Typ.	Max.	Unit
Operating voltage	V_{I1} V_{I2}	$V_O < V_{I2}$		0.9 0.9	—	2.0 2.0	V
Output voltage	V_O	$V_{I1}=1.5V$		4.80	5.00	5.20	V
Detection voltage*	V_{DET}			1.00	1.05	1.10	V
Hysteresis difference of* detection voltage	ΔV_{DET}			—	5	—	%
Operating supply current	I_{DDO}	SCI7631M/CAA SCI7632M/CAA	$V_{I1}=1.5V$ $I_O=1.0mA$	—	10	50	μA
		SCI7633M/CAA		—	—	—	
		SCI7635M/CAA SCI7636M/CAA	$V_{I1}=1.5V$ $f_{CLK}=32kHz$ $I_O=1.0mA$	—	5	30	
Stand-by supply current	I_{DDS}	$V_{I1}=1.5V$		—	3	10	μA
Switching transistor on resistance	R_{SWON}	$V_{I1}=1.5V$ $V_O=5.0V$ $V_{SW}=0.2V$		—	5	10	Ω
Switching transistor leakage current	I_{SWO}	$V_{I1}=1.5V$ $V_O=1.5V$ $V_{SW}=7.0V$		—	—	0.5	μA
Back-up switch on resistance*	R_{BSON}	$V_{I1}=1.0V$ $V_{I2}=3.0V$ $I_O=1.0mA$		—	50	100	Ω
Back-up switch leakage current*	I_{BSO}	$V_{I1}=1.0V$ $V_O=5.0V$ $V_{I2}=3.0V$		—	—	0.1	μA
Output current (\bar{RST} pin, \bar{V}_{DETOUT} pin)	I_{OL}	$V_{I1}=0.9V$ $V_{DS}=0.2V$		0.05	0.15	—	mA
Pull-up current (\bar{PS} pin)	I_{IH}	$V_{I1}=1.5V$		—	—	0.5	μA
Booster clock frequency	f_{CLK}	SCI7631M/CAA	$V_{I1}=1.5V$	30	40	50	kHz
		SCI7632M/CAA		30	45	55	

*The asterisked characteristic is not applicable to the SCI7633M/CAA.

SCI7630M/C

●SCI7631M/C_{BA}, SCI7633M/C_{BA}, SCI7635M/C_{BA}, SCI7636M/C_{BA}, SCI7637M/C_{BA}
(GND=0V, Ta=25°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Operating voltage	V _{I1} V _{I2}	V _O > V _{I2}	0.9 0.9	—	2.0 2.0	V
Output voltage	V _O	V _{I1} =1.5V	2.90	3.00	3.10	V
Detection voltage *	V _{DET}		1.00	1.05	1.10	V
Hysteresis difference of detection voltage *	ΔV _{DET}		—	5	-	%
Operating supply current	I _{DDO}	SCI7631M/C _{BA} V _{I1} =1.5V I _{OUT} =1.0mA	—	8	40	μA
		SCI7633M/C _{BA}	—	-	-	
		SCI7635M/C _{BA} SCI7636M/C _{BA} SCI7637M/C _{BA} V _{I1} =1.5V f _{CLK} =32kHz I _O =1.0mA	—	4	20	
Stand-by supply current	I _{DDS}	V _{I1} =1.5V	—	3	10	μA
Switching transistor on resistance	R _{SWON}	V _{I1} =1.5V V _O =3.0V V _{SW} =0.2V	—	6	12	Ω
Switching transistor leakage current	I _{SWQ}	V _{I1} =1.5V V _O =1.5V V _{SW} =7.0V	-	-	0.5	μA
Back-up switch on resistance*	R _{BSON}	V _{I1} =1.0V V _{I2} =2.0V I _O =1.0mA	-	70	160	Ω
Back-up switch leakage current*	I _{BSQ}	V _{I1} =1.0V V _O =3.0V V _{I2} =2.0V	-	-	0.1	μA
Output current (RST pin, V _{DETOUT} pin)	I _{OL}	V _{I1} =0.9V V _{DS} =0.2V	0.05	0.15	-	mA
Pull-up current (PS pin)	I _{IH}	V _{I1} =1.5V	-	-	0.5	μA
Booster clock frequency	f _{CLK}	SCI7631M/C _{BA}	V _{I1} =1.5V	30	40	50
						kHz

* The asterisked characteristic is not applicable to the SCI7633M/C_{BA} and SCI7637M/C_{BA}.

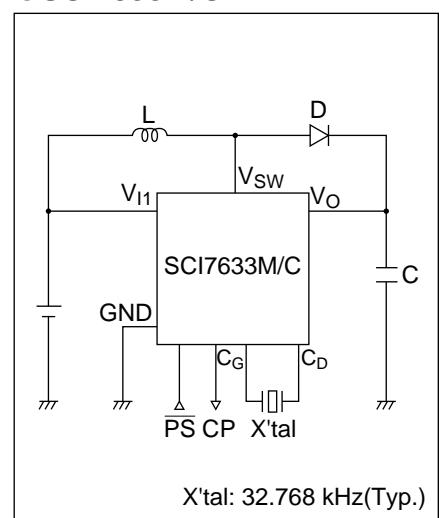
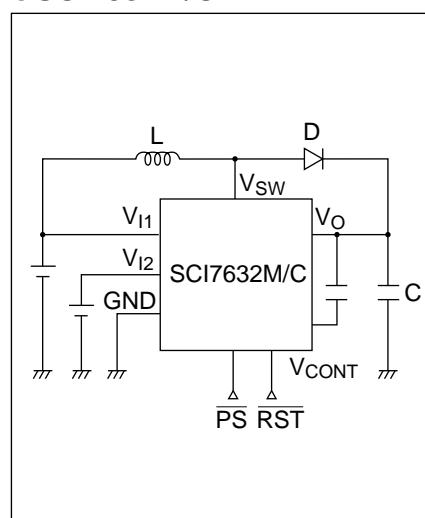
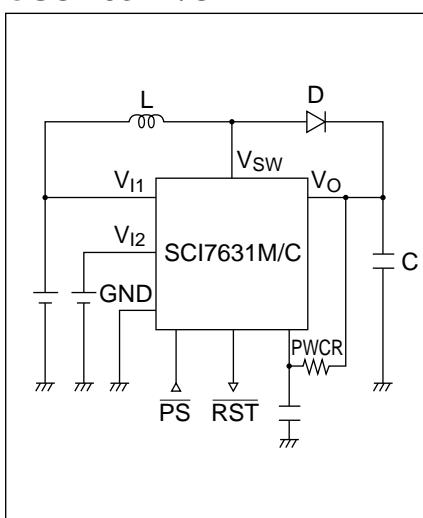
**For another characteristics, please inquire IC sales section.

■ BASIC EXTERNAL CONNECTION

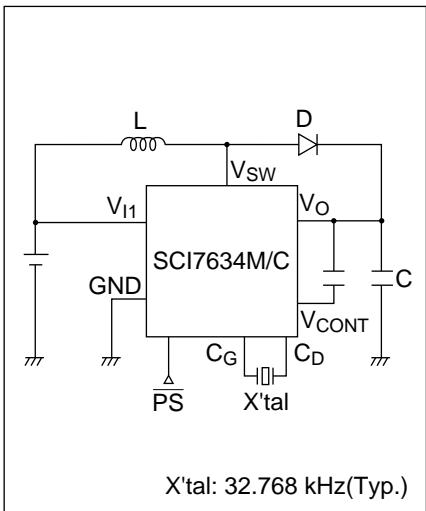
●SCI7631M/C

●SCI7632M/C

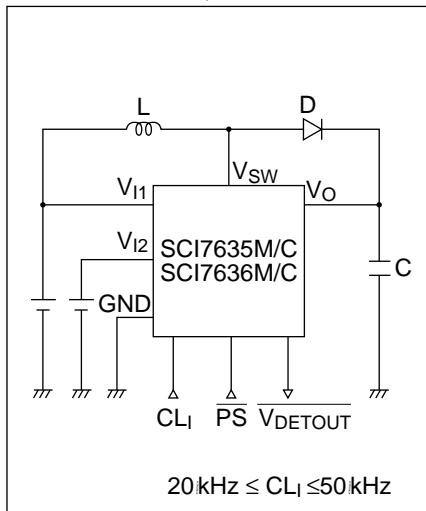
●SCI7633M/C



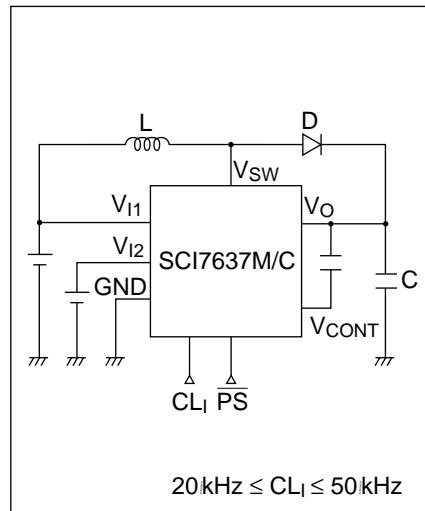
●SCI7634M/C



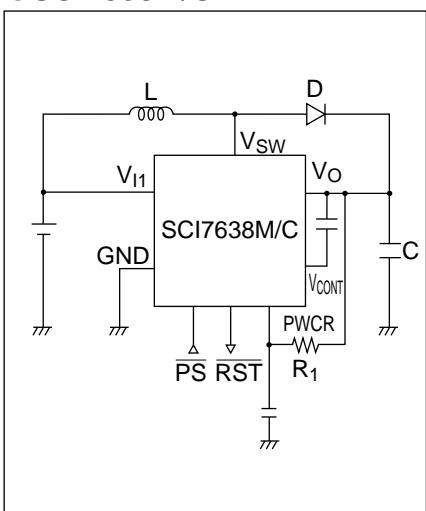
●SCI7635M/C, SCI7636M/C



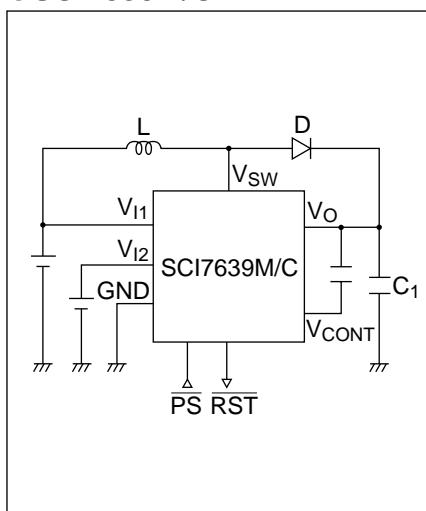
●SCI7637M/C



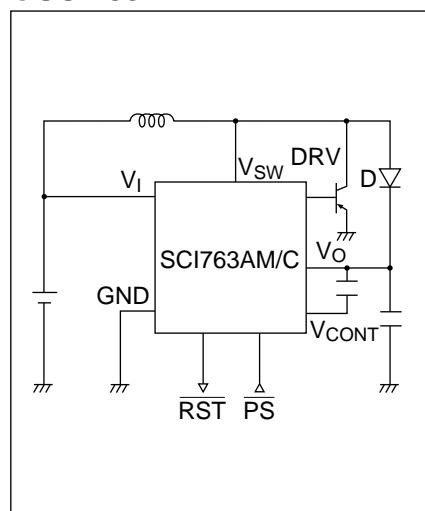
●SCI7638M/C



●SCI7639M/C



●SCI763AM



* $100\mu\text{H} \leq L \leq 1\text{mH}$, $C \geq 10\mu\text{F}$, D: Schottky diode

The boosting performance depends on the external parts(such as the inductor)and switching frequency.

Examples with SCI7631M/C AA, SCI7633M/C AA, SCI7635M/CAA and SCI7636M/C_{AA}

$L=220\mu\text{H}$, $V_{I1}=1.5\text{V}$, $f_{CLK}=32\text{kHz}$, $I_o=4\text{mA}$, $P_{eff}=70\%$

(leadless inductor used)

$L=220\mu\text{H}$, $V_{I1}=1.5\text{V}$, $f_{CLK}=32\text{kHz}$, $I_o=6\text{mA}$, $P_{eff}=75\%$

(drum type inductor used)

$L=300\mu\text{H}$, $V_{I1}=1.5\text{V}$, $f_{CLK}=32\text{kHz}$, $I_o=7\text{mA}$, $P_{eff}=80\%$

(toroidal inductor used)

Examples with SCI7631M/C BA, SCI7633M/CBA, SCI7635M/CBA and SCI7636M/C_{BA}

$L=220\mu\text{H}$, $V_{I1}=1.5\text{V}$, $f_{CLK}=32\text{kHz}$, $I_o=8\text{mA}$, $P_{eff}=70\%$

(leadless inductor used)

$L=220\mu\text{H}$, $V_{I1}=1.5\text{V}$, $f_{CLK}=32\text{kHz}$, $I_o=9\text{mA}$, $P_{eff}=75\%$

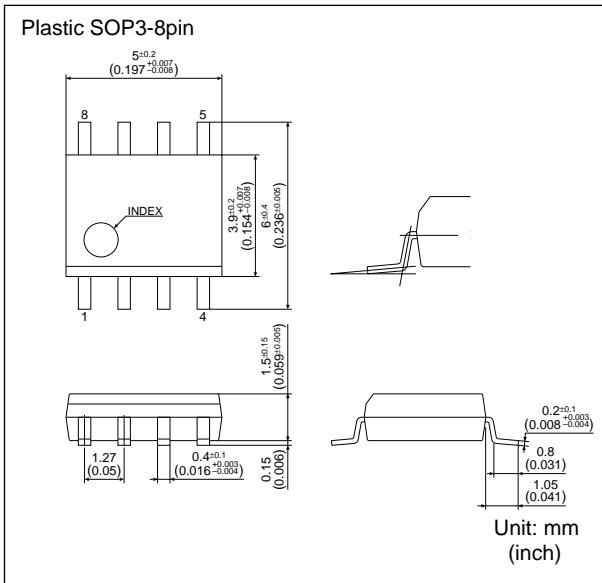
(drum type inductor used)

$L=300\mu\text{H}$, $V_{I1}=1.5\text{V}$, $f_{CLK}=32\text{kHz}$, $I_o=10\text{mA}$, $P_{eff}=80\%$

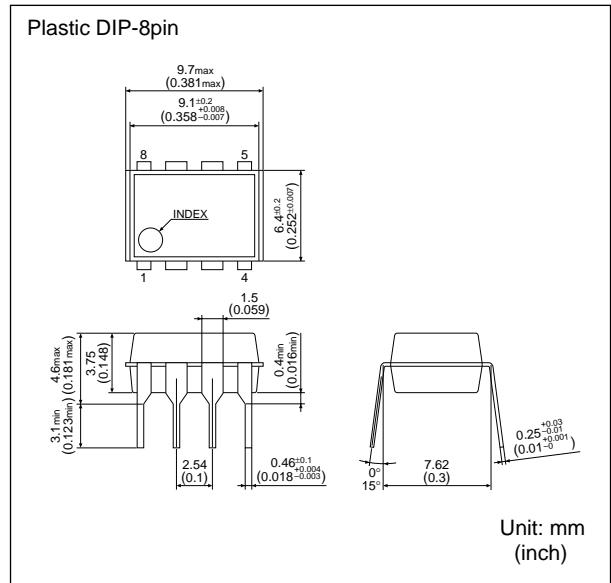
(toroidal inductor used)

■ PACKAGE DIMENSIONS

● SCI763xM

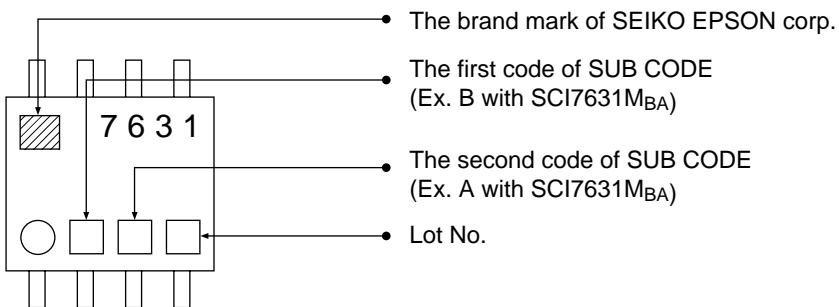


● SCI763xC



■ MARKING

A subcode is printed on SCI763xM below, because its package is very small.



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